

SWARNANDHRA

COLLEGE OF ENGINEERING & TECHNOLOGY

(AUTONOMOUS)

Accredited by National Board of Accreditation, AICTE, New Delhi, Accredited by NAAC with "A" Grade – 3.32 CGPA Recognized under 2(f) & 12(B) of UGC Ad. 1956, Approved by ACTE, New Delhi, Permanent Affiliation to JNTUK Kakinada Seetharampuram, W.G.DT., Narsapur-534280, (Andhra Pradesh)

DEPARTMENT OF ELECTRONICS AND COMMUNICATION ENGINEERING **TEACHING PLAN**

	Course Course Title		C- 10141				C- 70'41		Course Title Semester Bra		ches Contact Periods /Week		mic r	Date of commencement of Semester	
20EC3T0	ELECTRONIC CIRCUITS-1	III		ECE	5	2021-2	022	25-10-2021							
COURS	SE OUTCOMES														
	After completion of	the cours	e stude	nts are able to											
1	Explain the characterist	ics of diff	ferent s	emiconductor	diodes and	its applic	ations	(K2)							
2	Describe the characteris														
3	Construct the wave shap														
4	Analyze and design the Oscillators using BJT(K4)														
UNIT	Out Comes / Bloom's Level	Topics No.		Topics/Activit	y .	Text Book / Reference	Contac Hour								
			SEMIC	CONDUCTOR	DIDES AN	IS IT'S APPLICATIONS									
		1.1	Band s	structure of pn	junction,	T1, T3	T1, T3 1								
		1.2		t components,		T1, T3	1								
		1.3		mpere charact		T1, T3	1								
		1.4		tion and diffu		T1, T3									
			capaci diodes	tance of p-n ju	unction		1								
	CO1: Explain the characteristics of	1.5	Break	down of juncti		T1, T3	1	Chalk &							
	different			e bias, Zener a				Talk, Smar							
1	semiconductor diodes & transistors and its	1.6	TUNN	NEL Diode: Op		T1, T3	1	Board and							
	applications (K2)	1.7		aracteristics as a Switch.			1								
		1.8	Proble			T1, T2	2								
		1.9		iers: Half wav	e,	T1, T2	1								
		1.10		vave: center Rectifiers		T1, T2	1								
		1.11	Bridge	e type, analysi		T1, T2	1								

different parameters: PIV,

				Total	10	
	1					
		3.9	Relevant problems.	T2, T3	2	
		3.8	Stabilization.	T2, T3	1	
		3.7	Voltage- Divider Biasing	T2, T3	1	
		3.6	Self-Bias Configuration	T2, T3	1	
		3.5	configuration,	12, 13	1	
		3.5	Introduction, Fixed-Bias	T2, T3		
			MOSFET.FET & MOSFET BIASING:		1	
		3.4	Comparison between JFET and	T2, T3	1	PPT
3		2.4	channel).	TO TO		Board ar
3	biasing. (K1)		MOSFET (P-channel & N-			Talk, Sm
	1		Enhancement and Depletion		I	Chalk &
	Transistors, FET and		comparative study of			
	characteristics of	3.3	Characteristics and	T2, T3		
	CO2-Describe the	3.2	MOSFET-construction,	T2, T3	1	1
			parameters,			1
			operation, characteristics,		1	
		3.1	FET types, construction,	T2, T3		
			S & UJT CHARACTERISTICS			
		T = ===		Total	15	
		2.13	Problems	T1, T3	3	
		2.12	Transistor as a Switch	T1, T3	1	
			stabilization circuits,			
		2.11	Stabilization, various	T1, T3	1	
		2.10	Self Bias and problems,	T1, T3	1	
		2.9	Emitter Feed Back Bias,	T1, T3	1	
		2.8	Collector Feedback Bias,	T1, T3	1	+
			Fixed Bias and problems	T1, T3	1	-
		2.7		T1 T2	1	-
	biasing. (K1)	2.0	AC load lines,	11, 13	1	PPT
2	Transistors, FET and	2.6	The operating Point, DC &	T1, T3		Board an
2	characteristics of		characteristics.		1	Talk, Sma
	CO2-Describe the	2.3	and CC configurations, their	11, 13	1	Chalk &
		2.5	Transistor as a device in CE	T1, T3		
			characteristics.		,	
		2.4	configurations, their	11,13	1	
		2.4	Transistor as a device in CB,	T1, T3		
		2.3	flow across the base regions,	11,13	1	
		2.2	Characteristics of the current	T1, T3	'	
		2.1	PNP junction transistors, NPN junction transistors,	T1, T3	1	
			CTION TRANSISTOR CHARA	T1, T3	1CS AN	DIASIIV
			Total	CERTICE		D DIACINA
		1.15	Problems	T1, T2	2 17	
		1.14	Capacitor filter,	T1, T2	1	
			in a rectifier circuit,			
		1.13	Types: Harmonic components	T1, T2	1	
		1.12	Filters: Need of filters,	T1, T2	1	
			regulation, etc.	m1 ma	•	

.,		4.1	Low pass RC circuits (step &	T1, T4	1			
	CO3: Construct the		square response)					
	wave shaping circuits of non sinusoidal	4.2	high pass RC circuits (step & square response)	T1, T4	1			
	signals. (K3)	4.3	High pass RC circuit as a Differentiator,	T1, T4	1	Chalk &		
		4.4	Low passes RC circuit as integrator	T1, T4	1	Talk, Smart Board and		
			Clipping circuits:			PPT		
		4.5	diode clippers,	T1, T4	1	11.1		
		4.6	transistor clippers, Transfer characteristics,	T1, T4	1			
		4.7	Slicers	T1, T4	1			
			Clamping circuits:	11, 17	1	-		
		4.8	clamping operations,	T1, T4	1	-		
		4.9	Clamping circuit theorem,		1	-		
			practical clamping circuits	T1, T4	ı			
		4.10	Relevant problems.	T1, T4	2			
			,	Total	11			
			MULTIVIBR					
		5.1	Multivibrators: classification	T1, T4	1			
		5.2	Design of bistable multivibrator	T1, T4	1			
		5.3	and analysis of bistable multivibrator		1			
5	CO4: Analyze and	5.4	Design and analysis of schimitt trigger	T1, T4	1			
	design the	5.5	Design of astable multivibrator	T1, T4	1			
	Multivibrators using	5.6	Aalysis of astable multivibrator		1			
	BJT(K4)	5.7	Design of monostable multivibrator	T1, T4	1			
		5.8	Analysis of monostable multivibrator		1			
		5.9	Types of Triggering circuits	T1, T4	1			
		5.10	Relevant problems.	T1, T4	2			
				Total	11			
		C	UMULATIVE PROPOSED P	ERIODS	64			
Text Bo								
S.No.	AUTHORS, BOOK	AUTHORS, BOOK TITLE, EDITION, PUBLISHER, YEAR OF PUBLICATION						
1.	J. Millman & C.Ha Edition,2003. (Uni	witching Waveforms - J. Millman and H. Taub, McGraw-Hill, -II nd Edition,						
2.								
Referen	ce Books:							
S.No.								
1.			devices & circuits'- Dhanpat Ra					
2.			Digital Circuits, PHIIV Edition					
3.		Suresh K	Lumar and A. Vallava Raj, "Elec		ces and	circuits",		

Web Detail	S	
1.	https://www.electronicsforu.com/resources/electronic-devices-and-circuit-theory	
2.	https://www.elprocus.com/types-of-clipper-and-clamper-circuits-and-applications/	

		Name	Signature with Date
i.	Faculty I	Mrs. G.B.Christina	
ii.	Faculty II, (for common Course)	Mr. I.V.Ravi Kumar	B
iii.	Course Coordinator	Mrs. G.B.Christina	
iv.	Module Coordinator	Dr.K.Balagmurugan	Balalut
v.	Programme Coordinator	Dr.B.S.Rao	Bulu

A Principal